



N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- ESD Protected Up To 2kV
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

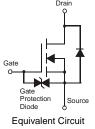
Mechanical Data

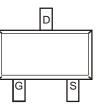
- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (approximate)





SOT523





Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN5L06TK-7	SOT523	3000/Tape & Reel

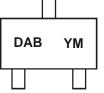
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



DAB = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 9 = September)

Date Code Key

Notes:

Year	200	6	2007		2008	20	09	2010		2011	2	2012
Code	Т		U		V	V	V	Х		Y		Z
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Drain Source Voltage		V _{DSS}	50	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current (Note 5)	Continuous	ID	280	mA

Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient	$R_{ ext{ heta}JA}$	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

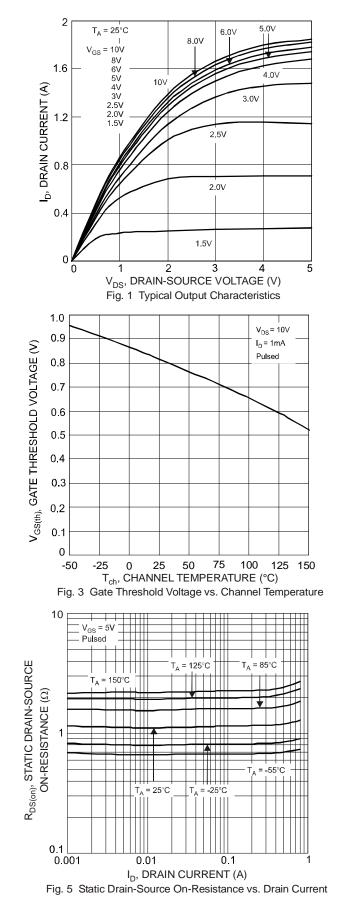
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage		BV _{DSS}	50	_	_	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	@ T _C = +25°C	IDSS	_		60	nA	$V_{DS} = 50V, V_{GS} = 0V$
Gate-Body Leakage		I _{GSS}	_	_	1 500 50	μA nA nA	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage		V _{GS(th)}	0.49		1.2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance		R _{DS (ON)}		1.8 1.5 1.2	3.0 2.5 2.0	Ω	$V_{GS} = 1.8V, I_D = 50mA$ $V_{GS} = 2.5V, I_D = 50mA$ $V_{GS} = 5.0V, I_D = 50mA$
On-State Drain Current		I _{D(ON)}	0.5	1.4	_	А	$V_{GS} = 10V, V_{DS} = 7.5V$
Forward Transconductance		Y _{fs}	200	_	—	mS	V _{DS} =10V, I _D = 0.2A
Source-Drain Diode Forward Voltage		V _{SD}	0.5	_	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS							
Output Capacitance C _{oss} — — 25 p		Ciss	_	_	50	pF	
		Coss	_		25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
		pF					

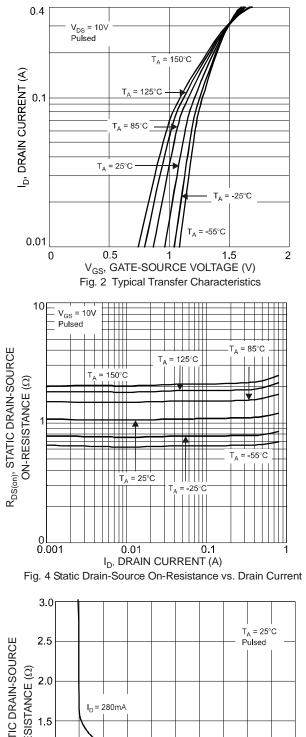
Notes:

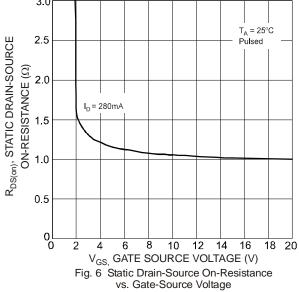
Device mounted on FR-4 PCB.
Short duration pulse test used to minimize self-heating effect.



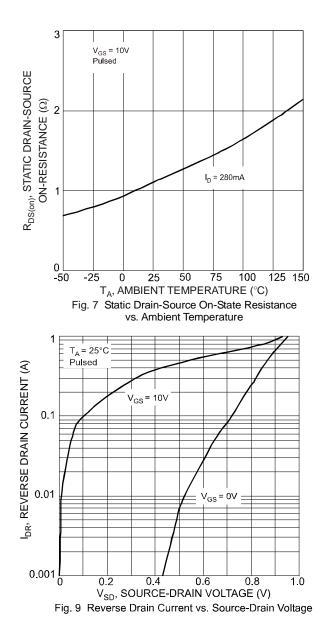
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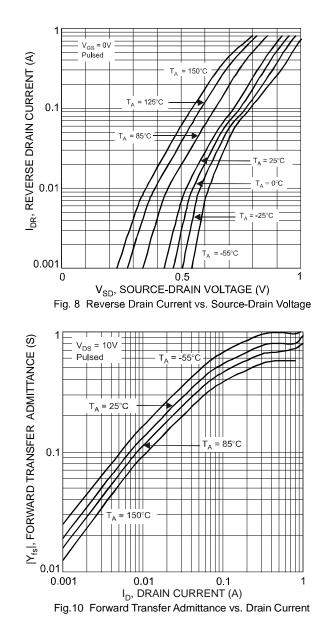






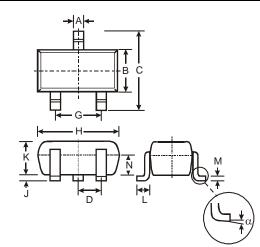






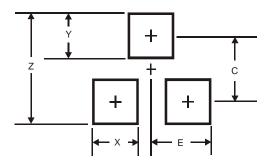


Package Outline Dimensions



SOT523						
Dim	Min	Max	Тур			
Α	0.15	0.30	0.22			
В	0.75	0.85	0.80			
С	1.45	1.75	1.60			
D			0.50			
G	0.90	1.10	1.00			
Н	1.50	1.70	1.60			
J	0.00	0.10	0.05			
Κ	0.60	0.80	0.75			
L	0.10	0.30	0.22			
М	0.10	0.20	0.12			
Ν	0.45	0.65	0.50			
α	0°	8°				
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Y	0.51
С	1.3
E	0.7



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